

**DESCRIPTION**

The M63834FP/KP 8-channel sinkdriver, consists of 8 PNP and 16 NPN transistors connected to form eight high current gain driver pairs.

**FEATURES**

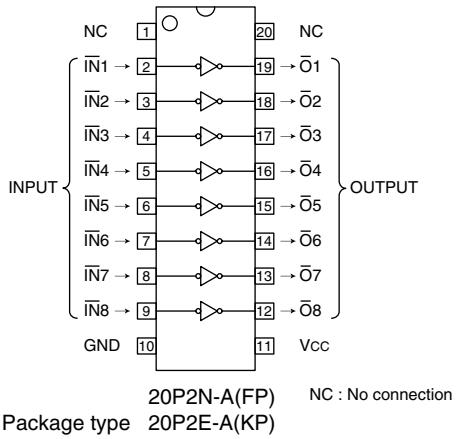
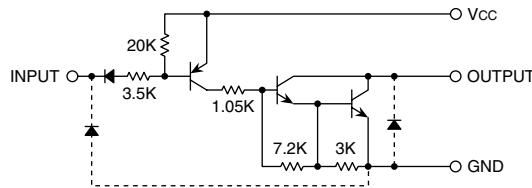
- High breakdown voltage ( $BV_{CEO} \geq 50V$ )
- High-current driving ( $I_C(max) = 500mA$ )
- 3V micro computer compatible input
- "L" active level input
- With input diode
- Wide operating temperature range ( $T_a = -40$  to  $+85^{\circ}C$ )

**APPLICATION**

Output for 3 voltage microcomputer series and interface with high voltage system. Relay and small printer driver, LED, or incandescent display digit driver.

**FUNCTION**

The M63834GP/KP is transistor-array of high active level eight units type which can do direct drive of 3 voltage microcomputer series. A resistor of  $3.5k\Omega$  is connected between the input and the base of PNP transistors. The input diode is intended to prevent the flow of current from the input to the Vcc. Without this diode, the current flows from "H" input to the Vcc and the "L" input circuit is activated, in such a case where one of the inputs of the 8 circuit is "H" and the other are "L" to save power consumption. The diode is inserted to prevent such mis-operation. The outputs are capable of driving 500mA and are rated for operation with output voltage up to 50V.

**PIN CONFIGURATION****CIRCUIT DIAGRAM**

The eight circuits share the Vcc and GND

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit :  $\Omega$

**ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted,  $T_a = -40 \sim +85^{\circ}C$ )**

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Supply voltage		7	V
VCEO	Collector-emitter voltage	Output, H	-0.5 ~ +50	V
Ic	Collector current	Current per circuit output, L	500	mA
VI	Input voltage		-0.5 ~ Vcc	V
Pd	Power dissipation	Ta = 25°C, when mounted on board	1.10(FP)/0.68(KP)	W
Topr	Operating temperature		-40 ~ +85	°C
Tstg	Storage temperature		-55 ~ +125	°C

Sep. 2001



**PRELIMINARY**  
Notice: This is not a final specification.  
Some parametric limits are subject to change.

RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted,  $T_a = -40 \sim +85^\circ C$ )

Symbol	Parameter	Limits			Unit
		min	typ	max	
V <sub>CC</sub>	Supply voltage	2.7	3.0	3.6	V
I <sub>C</sub>	Collector current (Current per 1 circuit when 8 circuits are coming on simultaneously)	Duty Cycle FP : no more than 4% KP : no more than 2%	0	—	400 mA
		Duty Cycle FP : no more than 15% KP : no more than 6%	0	—	200 mA
V <sub>IH</sub>	"H" input voltage	V <sub>CC</sub> -0.5	—	V <sub>CC</sub>	V
V <sub>IL</sub>	"L" input voltage	0	—	V <sub>CC</sub> -2.2	V

ELECTRICAL CHARACTERISTICS (Unless otherwise noted,  $T_a = -40 \sim +85^\circ C$ )

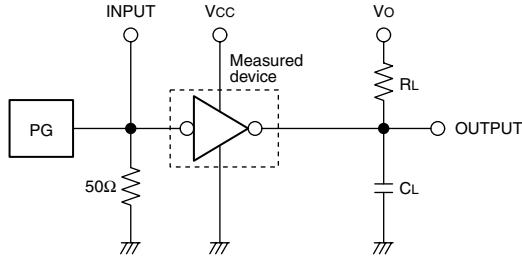
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ*	max	
V (BR) CEO	Collector-emitter breakdown voltage	I <sub>CEO</sub> = 100μA	50	—	—	V
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	V <sub>CC</sub> = 2.7V, V <sub>I</sub> = 0.5V, I <sub>C</sub> = 400mA	—	1.15	2.4	V
		V <sub>CC</sub> = 2.7V, V <sub>I</sub> = 0.5V, I <sub>C</sub> = 200mA	—	0.93	1.6	
I <sub>I</sub>	Input current	V <sub>I</sub> = V <sub>CC</sub> -2.2V	—	-220	-600	μA
I <sub>CC</sub>	Supply current (AN only Input)	V <sub>CC</sub> = 3.6V, V <sub>I</sub> = 0.5V	—	2.6	4.0	mA
h <sub>FE</sub>	DC amplification factor	V <sub>CC</sub> = 2.7V, V <sub>CE</sub> = 2V, I <sub>C</sub> = 0.35A, T <sub>a</sub> = 25°C	2000	10000	—	—

\* : Typical values are at  $T_a = 25^\circ C$

SWITCHING CHARACTERISTICS (Unless otherwise noted,  $T_a = 25^\circ C$ )

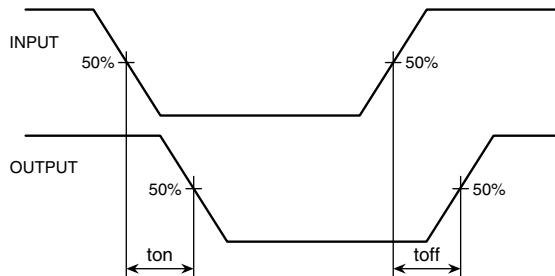
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t <sub>on</sub>	Turn-on time	C <sub>L</sub> = 15pF (note 1)	—	120	—	ns
t <sub>off</sub>	Turn-off time		—	4500	—	ns

## NOTE 1 TEST CIRCUIT



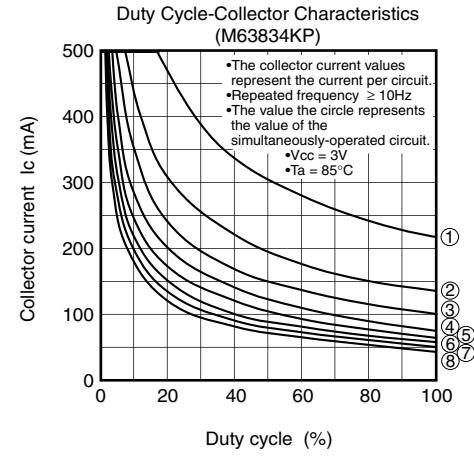
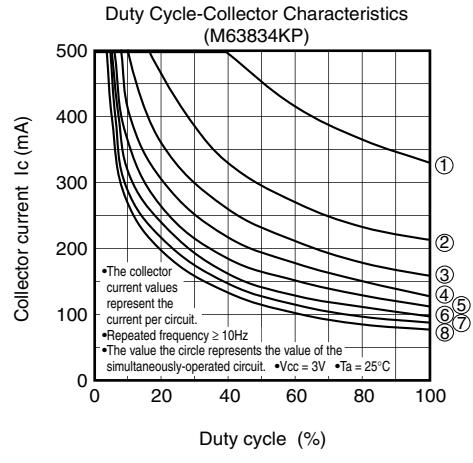
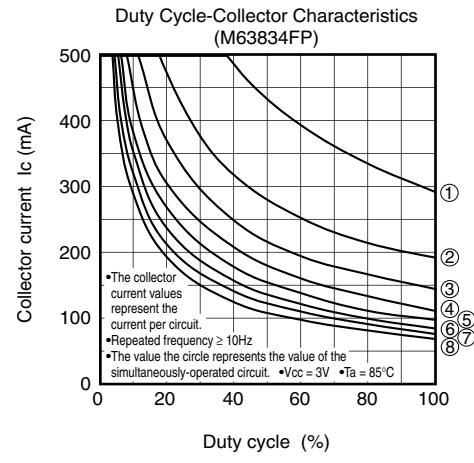
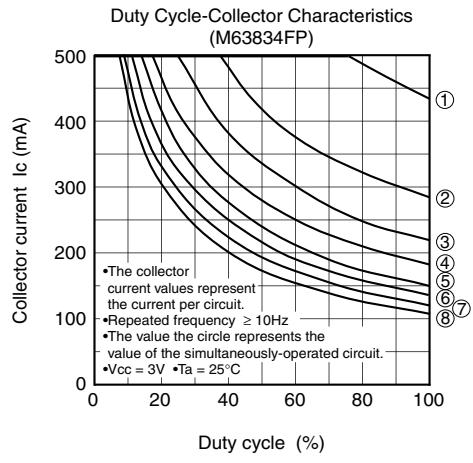
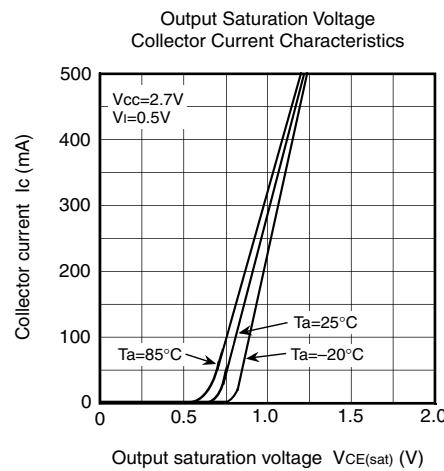
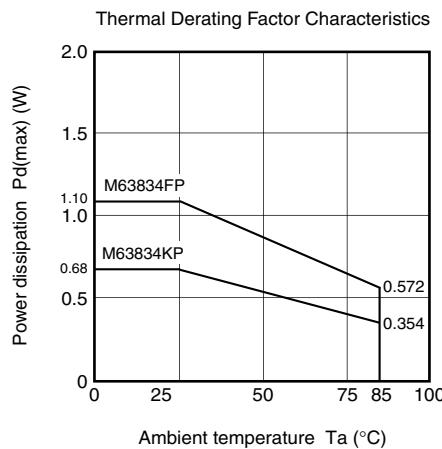
- (1) Pulse generator (PG) characteristics : PRR=1kHz,  $t_w = 10\mu s$ ,  $t_r = 6\mu s$ ,  $t_f = 6\mu s$ ,  $Z_0 = 50\Omega$ ,  $V_I = 0.5 \sim 2.7V$
- (2) Input-output conditions :  $R_L = 30\Omega$ ,  $V_o = 10V$ ,  $V_{CC} = 2.7V$
- (3) Electrostatic capacity  $C_L$  includes floating capacitance at connections and input capacitance at probes

## TIMING DIAGRAM



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#### TYPICAL CHARACTERISTICS



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